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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Leonard J. Olmer, *et al.*

Serial No.: 10/675,575

Filed: September 30, 2003

Title: IN-SITU REMOVAL OF SURFACE IMPURITIES PRIOR TO  
ARSENIC-DOPED POLYSILICON DEPOSITION IN THE  
FABRICATION OF A HETEROJUNCTION BIPOLAR  
TRANSISTOR

Grp./A.U.: 1792

Examiner: Jason Mark Heckert

Confirmation No.: 9967

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed  
with United States Patent and trademark Office on:  
December 15, 2008 (Date)

Elizabeth Schumacher  
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/  
(Signature of the person signing the certificate)

Sir:

**AMENDMENT UNDER 37 C.F.R. § 1.111**

In response to the Examiner's Action mailed September 16, 2008, please amend the above-  
identified application as follows: